

Parameter	Tr1 and Tr2
$V_{CC}$	50V
$I_{C(MAX.)}$	100mA
$R_1$	22k $\Omega$
$R_2$	22k $\Omega$

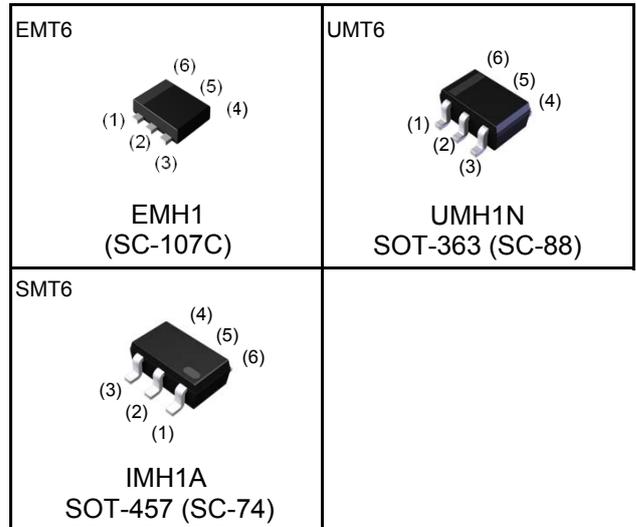
**●Features**

- 1) Built-In Biasing Resistors,  $R_1 = R_2 = 22k\Omega$ .
- 2) Two DTC124E chips in one package.
- 3) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see inner circuit).
- 4) The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of completely eliminating parasitic effects.
- 5) Only the on/off conditions need to be set for operation, making the circuit design easy.
- 6) Lead Free/RoHS Compliant.

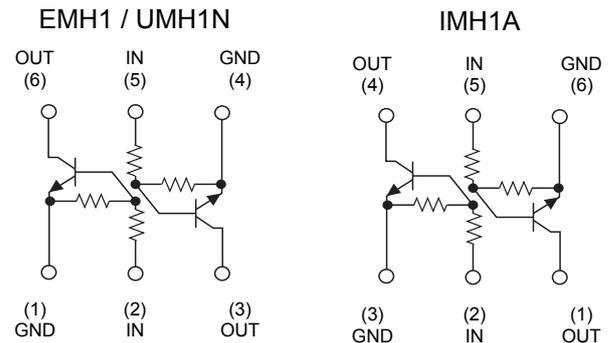
**●Application**

Inverter circuit, Interface circuit, Driver circuit

**●Outline**



**●Inner circuit**



**●Packaging specifications**

Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
EMH1	EMT6	1616	T2R	180	8	8,000	H1
UMH1N	UMT6	2021	TN	180	8	3,000	H1
IMH1A	SMT6	2928	T110	180	8	3,000	H1

●Absolute maximum ratings (Ta = 25°C)

<For Tr1 and Tr2 in common>

Parameter	Symbol	Values	Unit	
Supply voltage	$V_{CC}$	50	V	
Input voltage	$V_{IN}$	-10 to +40	V	
Output current	$I_O$	30	mA	
Collector current	$I_{C(MAX.)}^{*1}$	100	mA	
Power dissipation	EMH1 / UMH1N	$P_D^{*2}$	150 (Total) <sup>*3</sup>	mW
	IMH1A		300 (Total) <sup>*4</sup>	mW
Junction temperature	$T_j$	150	°C	
Range of storage temperature	$T_{stg}$	-55 to +150	°C	

●Electrical characteristics (Ta = 25°C)

<For Tr1 and Tr2 in common>

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Input voltage	$V_{I(off)}$	$V_{CC} = 5V, I_O = 100\mu A$	-	-	0.5	V
	$V_{I(on)}$	$V_O = 0.2V, I_O = 5mA$	3.0	-	-	
Output voltage	$V_{O(on)}$	$I_O / I_I = 10mA / 0.5mA$	-	0.1	0.3	V
Input current	$I_I$	$V_I = 5V$	-	-	0.36	mA
Output current	$I_{O(off)}$	$V_{CC} = 50V, V_I = 0V$	-	-	0.5	$\mu A$
DC current gain	$G_I$	$V_O = 5V, I_O = 5mA$	56	-	-	-
Input resistance	$R_1$	-	15.4	22	28.6	k $\Omega$
Resistance ratio	$R_2/R_1$	-	0.8	1	1.2	-
Transition frequency	$f_T^{*1}$	$V_{CE} = 10V, I_E = -5mA,$ $f = 100MHz$	-	250	-	MHz

\*1 Characteristics of built-in transistor

\*2 Each terminal mounted on a reference footprint

\*3 120mW per element must not be exceeded.

\*4 200mW per element must not be exceeded.

●Electrical characteristic curves(Ta = 25°C)

Fig.1 Input voltage vs. output current (ON characteristics)

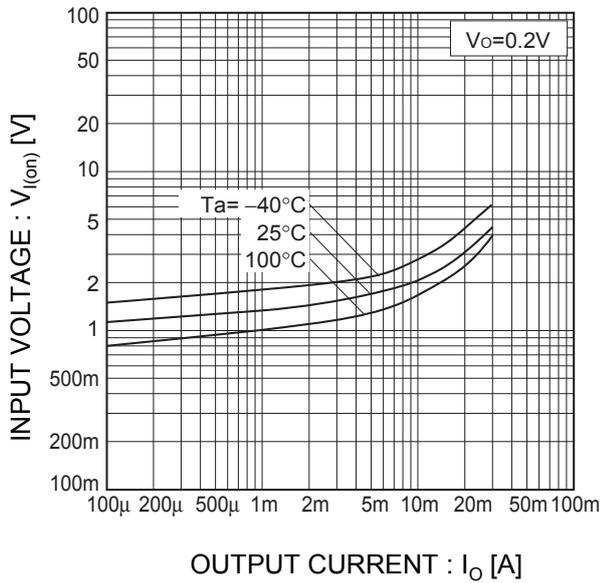


Fig.2 Output current vs. input voltage (OFF characteristics)

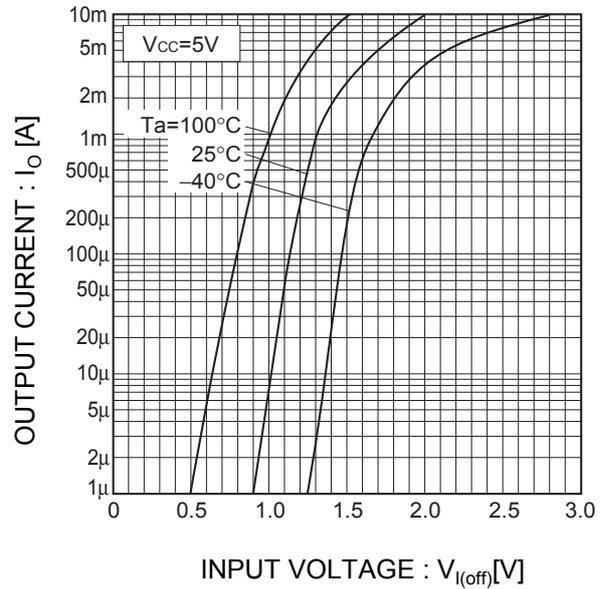


Fig.3 Output current vs. output voltage

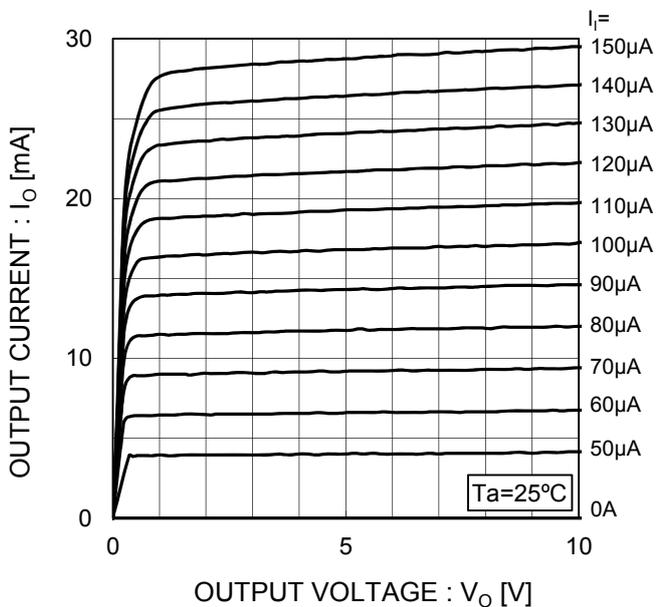
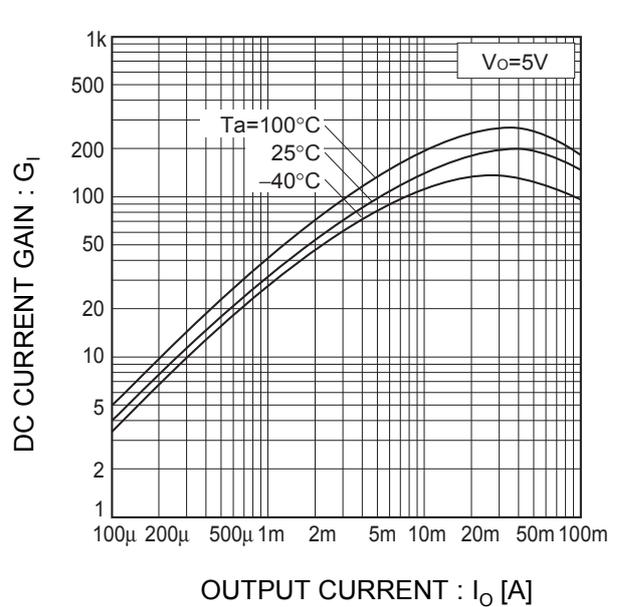
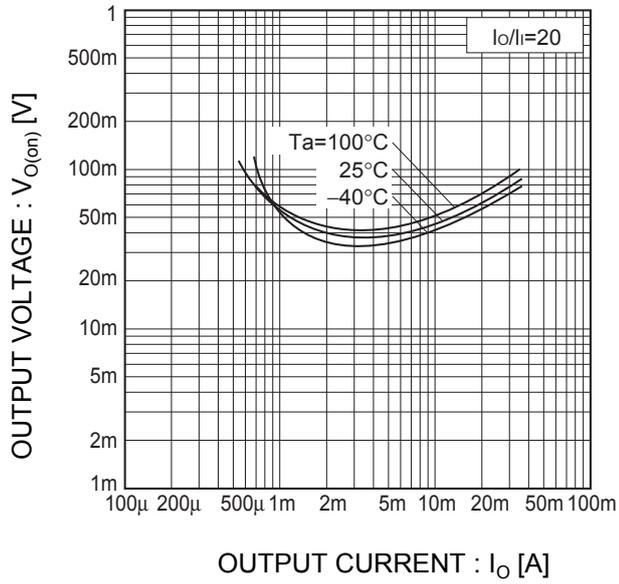


Fig.4 DC current gain vs. output current



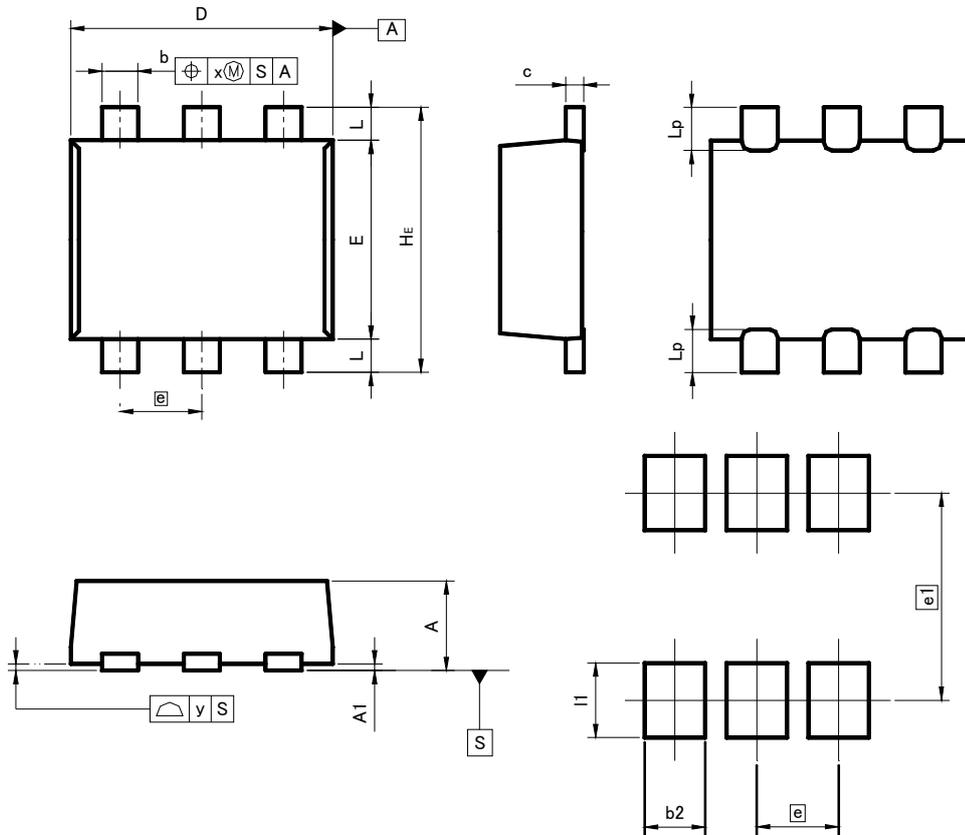
●Electrical characteristic curves(Ta = 25°C)

Fig.5 Output voltage vs. output current



●Dimensions (Unit : mm)

EMT6



**Pattern of terminal position areas**

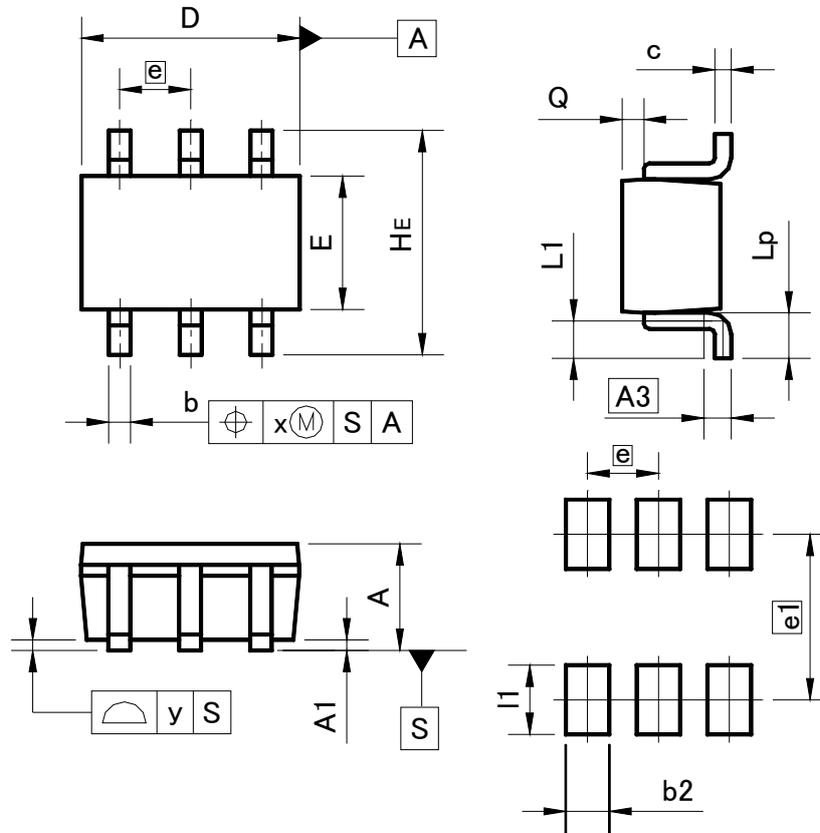
DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A1	0.00	0.10	0	0.004
A	0.45	0.55	0.018	0.022
b	0.17	0.27	0.007	0.011
c	0.08	0.18	0.003	0.007
D	1.50	1.70	0.059	0.067
E	1.10	1.30	0.043	0.051
e	0.50		0.02	
HE	1.50	1.70	0.059	0.067
L	0.10	0.30	0.004	0.012
Lp	-	0.35	-	0.014
x	-	0.10	-	0.004
y	-	0.10	-	0.004

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
e1	1.25		0.049	
b2	-	0.37	-	0.015
I1	-	0.45	-	0.018

Dimension in mm/inches

●Dimensions (Unit : mm)

UMT6



**Pattern of terminal position areas**

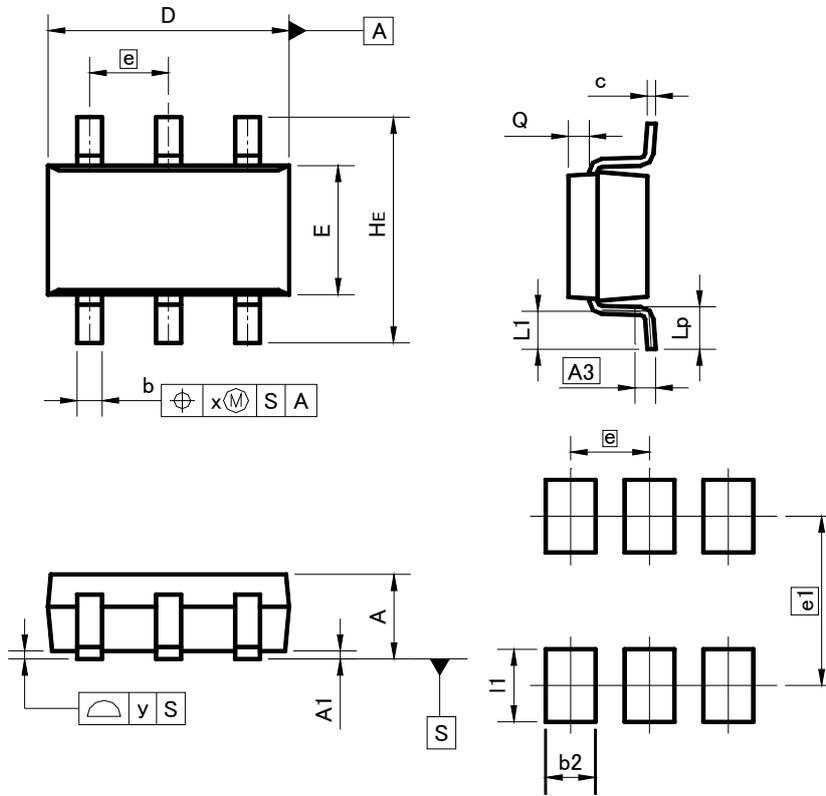
DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	0.80	1.00	-	0.039
A1	0.00	0.10	0	0.004
A3	0.25		0.01	
b	0.15	0.30	0.006	0.012
c	0.10	0.20	0.004	0.008
D	1.90	2.10	0.075	0.083
E	1.15	1.35	0.045	0.053
e	0.65		0.03	
HE	2.00	2.20	0.079	0.087
L1	0.20	0.50	0.008	0.02
Lp	0.25	0.55	0.01	0.022
Q	0.10	0.30	0.004	0.012
x	-	0.10	-	0.004
y	-	0.10	-	0.004

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
e1	1.55		0.06	
b2	-	0.40	-	0.016
h1	-	0.65	-	0.026

Dimension in mm/inches

●Dimensions (Unit : mm)

SMT6



Pattern of terminal position areas

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	1.00	1.30	0.039	0.051
A1	0.00	0.10	0	0.004
A3	0.25		0.01	
b	0.25	0.40	0.01	0.016
c	0.09	0.25	0.004	0.01
D	2.80	3.00	0.11	0.118
E	1.50	1.80	0.059	0.071
e	0.95		0.04	
HE	2.60	3.00	0.102	0.118
L1	0.30	0.60	0.012	0.024
Lp	0.40	0.70	0.016	0.028
Q	0.20	0.30	0.008	0.012
x	-	0.20	-	0.008
y	-	0.10	-	0.004

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
e1	2.10		0.08	
b2	-	0.60	-	0.024
l1	-	0.90	-	0.035

Dimension in mm/inches

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